

**Key Features** 

**Type TLRP Series** 

Up to 3 Watt at 70°C

12:06, 20:10, and 25:12 Packages Available

Low Inductance <5nH

AEC-Q200 Qualified

Sulfur Resistant unaffected by sulfur environments



TE Connectivity (TE) is pleased to offer these unique AEC-Q200 qualified High Power Metal Strip Resistors for Current Sensing positions. TLRP resistors have a special metal resistive element combined with suitable barrier layers beneath the solder to prolong terminal life. This model is particularly useful for power management along with DC-DC converting and charging applications, as well as adaptors within SWPS applications.

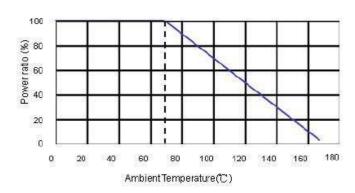
#### **Characteristics – Electrical**

Cizo	Power Rating	Re	Resistance Range (mΩ)					
Size	@ 70°C	±0.5%	±1%	±5%	(PPM/°C)			
		8, 10, 12,	15, 20, 25, 30	0, 33, 40,	±50			
1206	1W	3, 4, 5, 7,	8, 10, 12, 15,	18, 20, 22,	±75			
		25, 30, 33	3, 40, 47, 51, (	68, 75, 82,	±100			
		90, 100, 1	90, 100, 150					
2010	1W	10, 15, 20	±75					
2010	2W	10, 15, 20	1/3					
		39, 40, 47	7, 18, 20, 22, 2 , 50, 60, 68, 70 0, 120, 150, 18	, 75, 80, 82,	±25			
2512	2W & 3W	1, 2, 3, 4, 5 20, 22, 25 50, 51, 56 91, 100, 12	±50 ±75					

Operating Temperature Range: -55 ~ 170°C

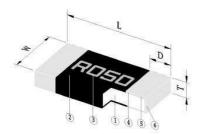
Operating Current = V(P/R), Operating Voltage = V(P\*R)

### **Derating**





### **Construction and Dimensions**



Alloy Plate	4	Internal Electrode	
② Overcoat	(3)	Barrier Layer	
3 Marking	6	Solder Plating	

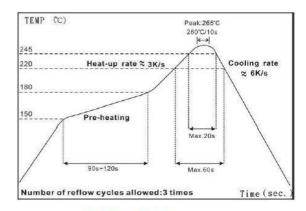
Туре	Size	L	W	Т	D
		mm	mm	mm	mm
TLRP2B	1206	3.15±0.10	1.45±0.10	0.55±0.10	0.55±0.15
TLRP2H	2010	5.00±0.10	2.40±0.15	0.60±0.10	0.80±0.20
TLRP3A	2512	6.40±0.25	3.20±0.25	0.70±0.20	0.90±0.30

# Marking

### **Resistance (4 Digit)**

Resistance	3mΩ	10mΩ	22mΩ	100mΩ
Codes	R003	R010	R022	R100

# **Solder Profile (Reflow)**



IR Reflow Soldering

(1) Time of IR reflow soldering at maximum temperature point 260°C: 10s



# **Environmental Characteristics**

Item	Requirement	Test Method
Temperature Coefficient of	As Spec.	IEC60115-1 4.8
Resistance (T.C.R.)		JIS-C-5201-1 4.8
		+25°C ~125°C, 25°C is the
		reference temperature
Short Time Overload	±1.0%	IEC60115-1 4.13
		JIS-C-5201-1 4.13
		5*rated power for 5 seconds
Insulation Resistance	≥10G	IEC60115-1 4.6
		JIS-C-5201-1 4.13
		100V DC for 1 minute
Endurance	±1.0%	IEC60115-1 4.25
		JIS-C-5201-1 4.25.1
		70±2°C, rated power for 1000 hrs
		with 1.5 hrs "ON" and 0.5 hr "OFF"
		MIL-STD-202 Method 108
		Condition D Steady State TA=125°C
		at derated power.
		Measurement at 24±4 hours after
		test conclusion.
Biased Humidity	±1.0%	MIL-STD-202 Method 103
		1000 hrs 85°C/85%RH 10% of
		operating power
Dry Heat	±1.0%	IEC60115-1 4.23.2
		JIS-C-5201-1 4.23.2
		MIL-STD-202 Method 108
		at +170°C for 1000 hrs
Resistance to Solvents	No visible damage on	MIL-STD-202 Method 215
	appearance and	Note: Add Aqueous wash chemical
	marking.	- OKEM Clean or equivalent.
		Do not use banned solvents.
Mechanical Shock	±1.0%	MIL-STD-202 Method 213
		Wave Form: Tolerance for half sine
		shock pulse.
		Peak value is 100g's. Normal
		duration(D) is 6.
Vibration	±1.0%	MIL-STD-202 Method 204
		5g's for 20 min., 12 cycles each of
		3 orientations.
		Note: Use 8"X5" PCB .031" thick 7
		secure points on one long side and
		2 secure points at corners of
		opposite sides. Parts mounted
		within 2" from any secure point.
		Test from 10-2000 Hz.
ESD	±1.0%	AEC-Q200-002
		Human body model, 2KV. (DC =
		Direct Contact Discharge)
Flammability	V-0	UL-94
		50W (20 mm) Vertical Burning
		Test. Electrical test not required.



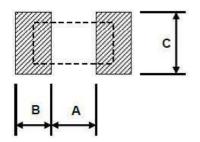
Item	Requirement	Test Method
Flame Retardance	The following	AEC-Q200-001
	phenomena cannot	Assemble the sample on the test
	occur during the	board, perform functional test
	experiment:	before flame retardant test to
	(1)A flame over 3.0	ensure no damage to the sample.
	seconds duration.	The test environment is 22±5 °C
	(2)An explosion.	still air, from 9.0 to 32.0 VDC
	(3)A temperature	(current clamped up to 500A),
	above 350°C	increase the voltages at the rate of
	sustained for over 10	1.0 VDC per hour until the end of
	seconds	the experiment.
Bending Strength	±1.0%	JIS-C-5201-1 4.33
		IEC-60115-1 4.33
		AEC-Q200-005
		Bending width 2mm once for 5
		seconds
Terminal Strength (SMD)	Not broken	AEC-Q200-006
		Force of 1.8kg for 60 seconds.
Solderability	95% min. coverage	JIS-C-5201-1 4.17
		IEC-60115-1 4.17
		J-STD-002
		245±5°C for 3seconds
Resistance to Soldering	±0.5%	JIS-C-5201-1 4.18
Heat		IEC-60115-1 4.18
		MIL-STD-202 Method 210
		260±5°C for 10 seconds
Rapid Change of	±1.0%	JIS-C-5201-1 4.19
Temperature		IEC-60115-1 4.19
		-55°C to +155°C, 5 cycles
Temperature Cycling	±1.0%	JESD22 Method JA-104
		1000 cycles (-55°C to +125°C,
		Dwell 30 minutes, transition time
		within 1 minute). Measurement at
		24±4 hours after test conclusion.
Low Temperature Storage	±1.0%	IEC60115-1 4.23.4
		JIS-C-5201-1 4.23.4
		at -55°C for 2hrs

RCWV (Rated Continuous Working Voltage)=  $V(P^*R)$  or Max. Operating Voltage whichever is lower.

Storage Temperature: 15~28°C; Humidity < 80%RH



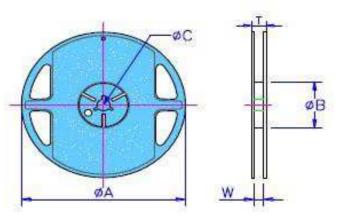
### **Recommended Land Pattern**



Size	A (mm)	B (mm)	C (mm)				
1206	1.50	1.40	1.70				
2010	3.60	1.40	2.50±0.2				
2512	4.00	2.00	3.50				
*FR4 conner hoard 100um of connerned thickness							

# **Packaging**

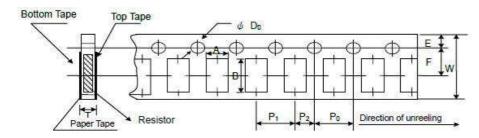
# Reel Specifications & Packaging Quantity



Size	Resistance (mΩ	Tape / Qty	Tape width	Reel Dia.	ØA (mm) ±1.5	ØB (mm)	ØC (mm )	W (mm)	T (mm )		
1206	3~40	Paper / 5K	8mm			60+1-0	13.0 ±0.2	9.0±0.5	12.5 ±0.5		
2010	10~100	Embossed / 4K	12mm	7 inch	-	-	178.5	60+1-0	13.0 ±0.5	13.0 ±0.5	15.5 ±0.5
2512	4~200	Embossed / 4K	12mm				inch	1/8.5	6011.0	13.0	13.0±1.
2512	3	Embossed / 2K	12mm			60±1.0	±0.5	0	±0.5		

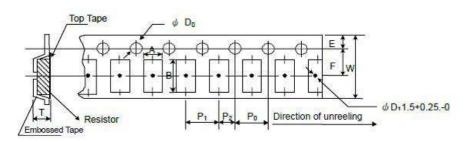


# Paper Tape Specification



Ī	Α	В	W	E	F	Po	P <sub>1</sub>	P <sub>2</sub>	ØD₀	Т
	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)
ĺ	1.90±	3.50±	8.0±	1.75±	3.50±	4.00±	4.00±	2.00±	1.50	0.85±
	0.10	0.20	0.20	0.10	0.05	0.10	0.05	0.05	+0.1,-0	0.10

### **Embossed Plastic Tape Specification**



	Α	В	W	E	F	Po	P <sub>1</sub>	P <sub>2</sub>	ØDο	Т	
	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	
2010	2.80	5.5	12.0	0.75	5.5	4.00	4.00	2.00	1.5 +0.1	1.20+0	
2010	±0.10	±0.10	±0.30	±0.10	±0.5	±0.10	±0.10	±0.05	-0	1.20+0	
2512	2 501	C 70:	12.01	1 75:	·	4.001	4.001	2.00+	1.50.01	1.20+0	
2512 3mΩ	3.50± 0.10	6.70± 0.10	12.0± 0.30	1.75± 0.10	5.5± 0.05	4.00± 0.10	4.00± 0.10	2.00± 0.05	1.50 +0.1 -0	1.45± 0.2	

#### **How To Order**

TLRP	2B	10	Ε	R008	F	TD
Common Part	Size	*Power Rating	**TCR (PPM/°C)	Resistance Code	Tolerance	Packaging
TLRP – Ultra Low Ohm Metal Strip Resistor	2B – 1206 2H - 2010 3A – 2512	1.0 = 10 2.0 = 20 3.0 = 30	C = ±25 D = ±50 W = ±75 E = ±100	R003 - $3mΩ$ R020 - $20mΩ$ R10 - $0.1Ω$ (100 $mΩ$ )	D = ±0.5% F = ±1% J = ±5%	TDG = 2000/Reel (2512 3mΩ) TE = 4000/Reel (2512) TD = 5000/Reel (1206)